

**Green Products** 

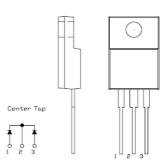
## SBRF30100CT SCHOTTKY RECTIFIER

### **Applications:**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

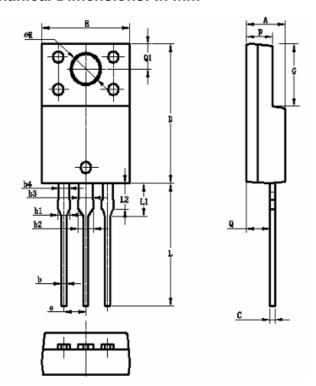
#### Features:

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



**OUTLINE DRAWING** 

#### **Mechanical Dimensions: In mm**



	OPTION 1(CJ)		OPTION	N 2(HD)	
Dim	Min Max		Min	Max	
Α	4.4	4.6	4.30	4.70	
b	0.6T	ΥP	0.50	0.75	
b1	1.3T	ΥP	1.30	1.40	
b2	1.7T	ΥP	1.70	1.80	
b3	1.6T	ΥP	1.50	1.75	
b4	1.2T	ΥP	1.10	1.35	
С	0.60	ГҮР	0.50	0.75	
D	14.8	15.1	14.80	15.20	
Е	10.06	10.26	9.96	10.36	
е	2.55TYP		2.54	2.54TYP	
F	2.9	3.1	2.80	3.20	
G	6.5	6.9	6.50	6.90	
L	12.7	13.7	12.8	13.2	
L1	3.4	3.8	3.60	4.00	
L2	2.6	3.0	-	-	
Q	2.5	2.9	2.50	2.90	
Q1	2.5 2.9		2.70REF		
ØR	3.5REF		3.50	REF	

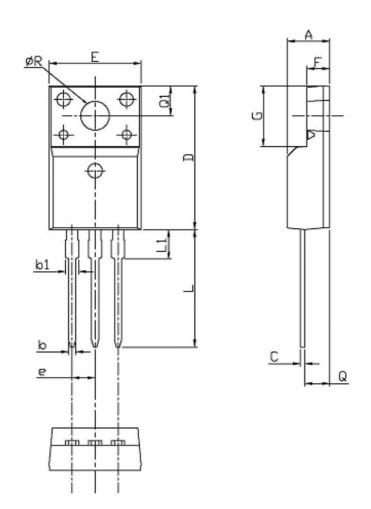
<sup>•</sup> Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

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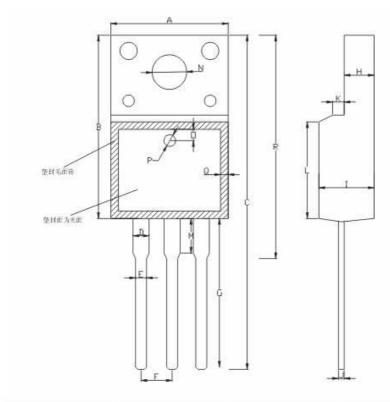
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	OPTION 3		OPTION 4		
Dim	Min	Max	Min	Max	
Α	4.53	4.93	4.50	4.90	
b	0.71	0.91	0.70	0.90	
b1	1.15	1.39	1.33	1.47	
С	0.36	0.53	0.45	0.60	
D	15.67	16.07	15.67	16.07	
E	9.96	10.36	9.96	10.36	
е	2.54TYP		2.54 BSC		
F	2.34	2.76	2.34	2.74	
G	6.50	6.90	6.48	6.88	
L	12.37	12.77	12.78	13.18	
L1	2.23	2.63	3.03	3.43	
Q	2.56	2.96	2.56	2.96	
Q1	3.10	3.50	3.10	3.50	
ØR	2.98	3.38	3.08	3.28	



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A:10.20	$\pm 0.50$	B:15.90	$\pm 0.50$	C:29.00	$\pm 1.00$	D:1.24	$\pm 0.10$
E:0.80	$\pm 0.10$	F:2.54	$\pm 0.10$	G:13.10	$\pm 1,0$	H:2.55	$\pm 0.05$
		J:0.50					$\pm 0.50$
M:3.00	±0.50	N:3.20	$\pm 0.20$	O:1,25	$\pm 0.05$	P:1.5	$\pm 0.05$
Q:1.0	±0.20	R:19.2	±1.0				

## **OPTION 5 (SR)**

#### **ITO-220AB**





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## **Marking Diagram:**



**Cautions:** Molding resin Epoxy resin UL:94V-0

Where XXXXX is YYWWL

SBR = Device Type F = Package type

30 = Forward Current (30A) 100 = Reverse Voltage (100V)

CT = Configuration

SSG = SSG YY = Year WW = Week L = Lot Number

## **Ordering Information:**

Device	Package	Shipping
CDDE20400CT	ITO-220AB	FOres / tube
SBRF30100CT	(Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	100	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> = 133℃, rectangular wave form	30	Α
Peak Repetitive Forward Current(per leg)	I <sub>FRM</sub>	Rated $V_R$ square wave, 20KHz $T_C$ = 133°C	20	Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	Surge applied at rated load conditions halfwave, single phase,60Hz	150	А

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#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	$V_{F1}$	@ 15 A, Pulse, T <sub>J</sub> = 25 °C	0.90	٧
	$V_{F2}$	@ 15 A, Pulse, T <sub>J</sub> = 125 °C	0.80	V
Max. Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}C$	1.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125  ^{\circ}\text{C}$	6.0	mA
Max. Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz$	400	pF
Typical Series Inductance (per leg)	Ls	Measured lead to lead 5 mm from package body	8.0	nΗ
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

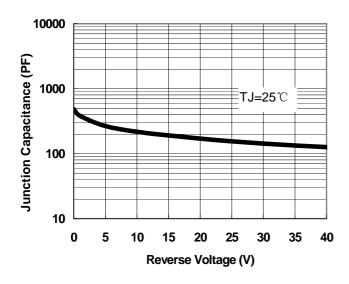
<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	3.0	°C/W
Maximum Thermal Resistance, Case to Heat Sink	$R_{ heta JA}$	DC operation	50	°C/W
Maximum Thermal Resistance, Case to Heat Sink	$R_{ heta CS}$	Mounting surface, smooth and greased	0.50	°C/W
Approximate Weight	wt	-	2.0	g
Case Style		ITO-220AB		



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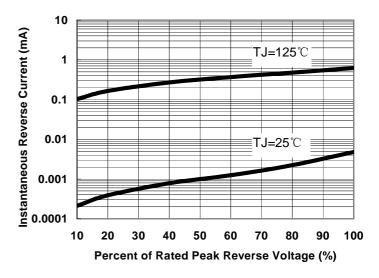


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

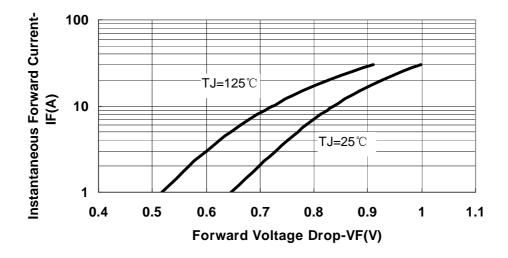


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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## **SBRF30100CT**

Technical Data Data Sheet N0925, Rev. A **Green Products** 

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